## NSN 5962-01-080-6498

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-080-6498 **Body Length:** Between 0.370 inches and 0.410 inches **Body Width:** Between 0.245 inches and 0.280 inches **Body Height:** Between 0.030 inches and 0.070 inches **Maximum Power Dissipation Rating:** 256.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Countermeasures set, type an/alq-137 **Features Provided:** Hermetically sealed and monolithic and positive outputs and low power and schottky and 3-state output and programmed and programmable and bipolar and w/decoded output and w/enable and w/storage and expandable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 94117-310412 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 flat leads Shelf Life: N/a **Unit Of Measure:** 

Demilitarization: Yes - demil/mli

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Memory Microcircuit - Page 2 of 2



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